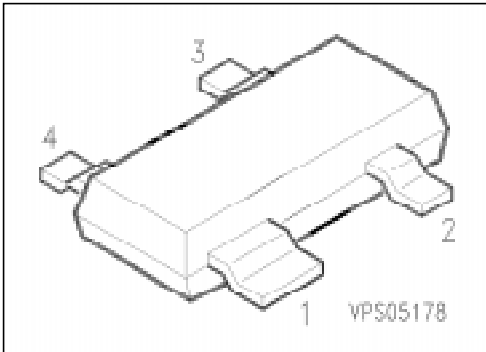


Silicon Switching Diode Array

BAS 28

- For high-speed switching
- Electrically insulated diodes



Type	Marking	Ordering Code (tape and reel)	Pin Configuration	Package ¹⁾
BAS 28	JTs	Q62702-A77		SOT-143

Maximum Ratings

Parameter	Symbol	Values	Unit
Reverse voltage	V_R	75	V
Peak reverse voltage	V_{RM}	85	
Forward current	I_F	200	mA
Surge forward current, $t = 1 \mu s$	I_{FS}	4.5	A
Total power dissipation, $T_s = 31^\circ C$	P_{tot}	330	mW
Junction temperature	T_j	150	$^\circ C$
Storage temperature range	T_{stg}	- 65 ... + 150	

Thermal Resistance

Junction - ambient ²⁾	$R_{th JA}$	≤ 500	K/W
Junction - soldering point	$R_{th JS}$	≤ 360	

¹⁾ For detailed information see chapter Package Outlines.

²⁾ Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm² Cu.

Electrical Characteristics

at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

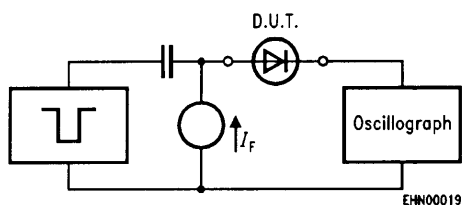
DC characteristics

Breakdown voltage $I_{(BR)} = 100\text{ }\mu\text{A}$	$V_{(BR)}$	85	—	—	V
Forward voltage $I_F = 1\text{ mA}$ $I_F = 10\text{ mA}$ $I_F = 50\text{ mA}$ $I_F = 150\text{ mA}$	V_F	— — — —	— — — —	715 855 1000 1250	mV
Reverse current $V_R = 75\text{ V}$ $V_R = 25\text{ V}, T_A = 150\text{ }^{\circ}\text{C}$ $V_R = 75\text{ V}, T_A = 150\text{ }^{\circ}\text{C}$	I_R	— — —	— — —	1 30 50	μA

AC characteristics

Diode capacitance $V_R = 0\text{ V}, f = 1\text{ MHz}$	C_D	—	—	2	pF
Reverse recovery time $I_F = 10\text{ mA}, I_R = 10\text{ mA}, R_L = 100\text{ }\Omega$ measured at $I_R = 1\text{ mA}$	t_{rr}	—	—	6	ns

Test circuit for reverse recovery time

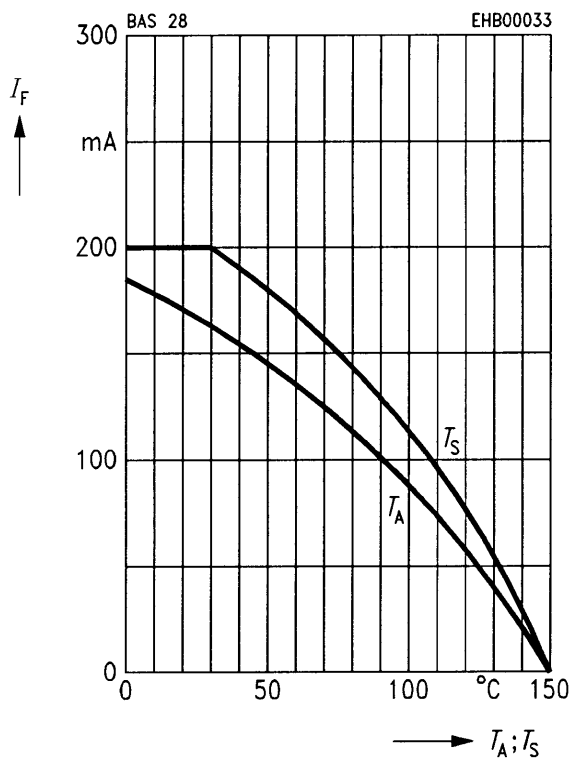


Pulse generator: $t_p = 100\text{ ns}$, $D = 0.05$
 $t_r = 0.6\text{ ns}$, $R_i = 50\text{ }\Omega$

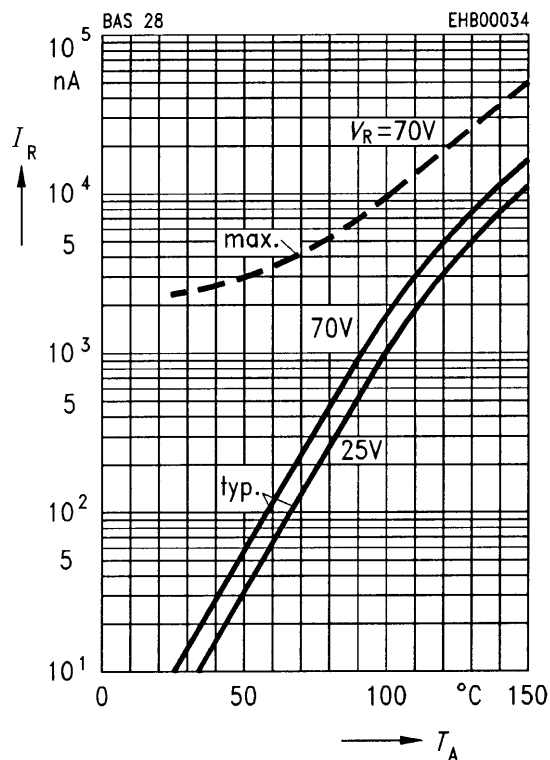
Oscilloscope: $R = 50\text{ }\Omega$
 $t_r = 0.35\text{ ns}$
 $C \leq 1\text{ pF}$

Forward current $I_F = f(T_A^*; T_S)$

* Package mounted on epoxy

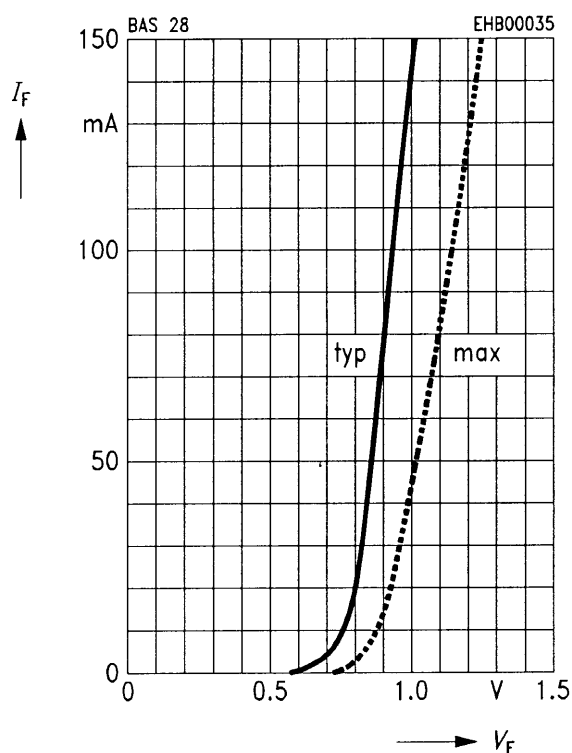


Reverse current $I_R = f(T_A)$



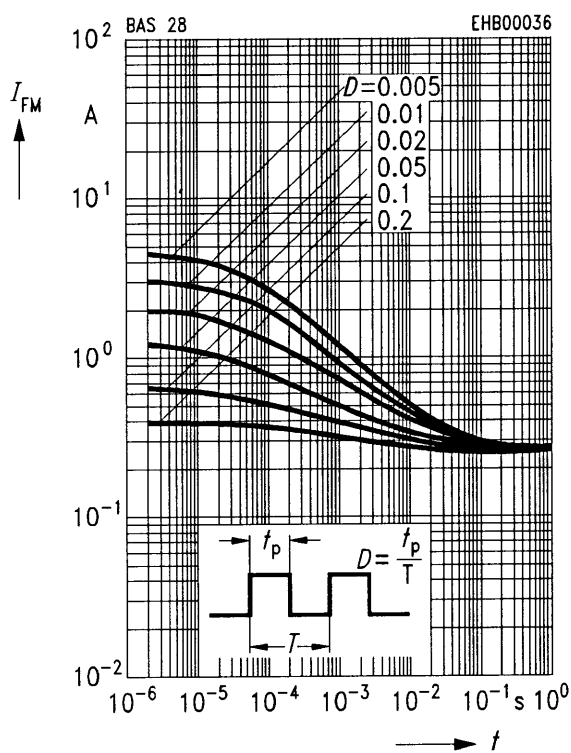
Forward current $I_F = f(V_F)$

$T_A = 25\text{ °C}$



Peak forward current $I_{FM} = f(t)$

$T_A = 25\text{ °C}$



Forward voltage $V_F = f(T_A)$

